1PS66SB82; 1PS88SB82

15 V, 30 mA low C_d Schottky barrier diodes Rev. 04 — 13 January 2010

Product data sheet

1. **Product profile**

1.1 General description

Epitaxial low capacitance Schottky barrier diodes encapsulated in very small SMD plastic packages.

Table 1. **Product overview**

Type number	Package		Configuration
	NXP	JEITA	
1PS66SB82	SOT666	-	triple isolated diode
1PS88SB82	SOT363	SC-88	triple isolated diode

1.2 Features

- Low diode capacitance
- Low forward voltage
- Very small SMD plastic packages

1.3 Applications

- Digital applications:
 - Ultra high-speed switching
 - Clamping circuits
- RF applications:
 - Diode ring mixer
 - RF detector
 - RF voltage doubler

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	continuous forward current		-	-	30	mA
V_R	continuous reverse voltage		-	-	15	V
C _d	diode capacitance	$V_R = 0 V;$ f = 1 MHz; see <u>Figure 4</u>	-	1	-	pF



2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline	Symbol
1	anode (diode 1)		
2	anode (diode 2)	6 5 4	6 5 4
3	anode (diode 3)		
4	cathode (diode 3)		1 2 3
5	cathode (diode 2)		sym046
6	cathode (diode 1)	001aab555	

3. Ordering information

Table 4. Ordering information

Type number	Package	Package				
	Name	Description	Version			
1PS66SB82	-	plastic surface mounted package; 6 leads	SOT666			
1PS88SB82	SC-88	plastic surface mounted package; 6 leads	SOT363			

4. Marking

Table 5. Marking codes

Type number	Marking code
1PS66SB82	N5
1PS88SB82	E1*

^{[1] * = -:} made in Hong Kong

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{R}	continuous reverse voltage		-	15	V
I _F	continuous forward current		-	30	mA
Tj	junction temperature		-	125	°C
T _{amb}	ambient temperature		–65	+125	°C
T _{stg}	storage temperature		–65	+150	°C

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u>			
	SOT666		[2][3]	-	700	K/W
	SOT363		[3][4]	-	416	K/W

^[1] For Schottky barrier diodes thermal run-away has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and I_{F(AV)} rating will be available on request.

- [2] Refer to SOT666 standard mounting conditions.
- [3] Reflow soldering is the only recommended soldering method.
- [4] Refer to SOT363 (SC-88) standard mounting conditions.

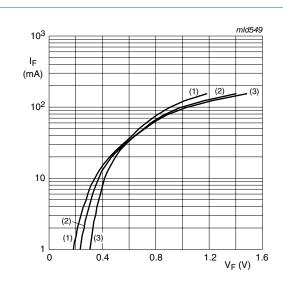
7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

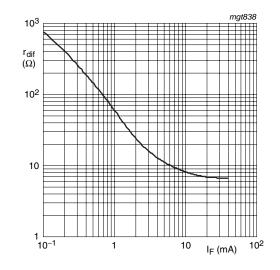
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	see Figure 1	<u>[1]</u>			
		I _F = 1 mA	-	-	340	mV
		$I_F = 30 \text{ mA}$	-	-	700	mV
I _R	reverse current	V _R = 1 V; see Figure 2	-	-	0.2	μΑ
r _{dif}	differential resistance	$I_F = 5 \text{ mA}$; $f = 1 \text{ kHz}$; see Figure 3	-	12	-	Ω
C _d	diode capacitance	$V_R = 0 V$; $f = 1 MHz$; see Figure 4	-	1	-	pF

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$



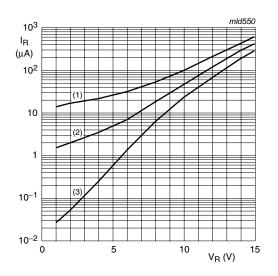
- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



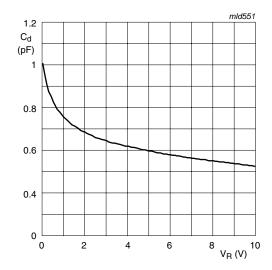
f = 1 kHz; T_{amb} = 25 °C

Fig 3. Differential diode forward resistance as a function of forward current; typical values



- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values



 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^{\circ}\text{C}$

Fig 4. Diode capacitance as a function of reverse voltage; typical values

8. Package outline

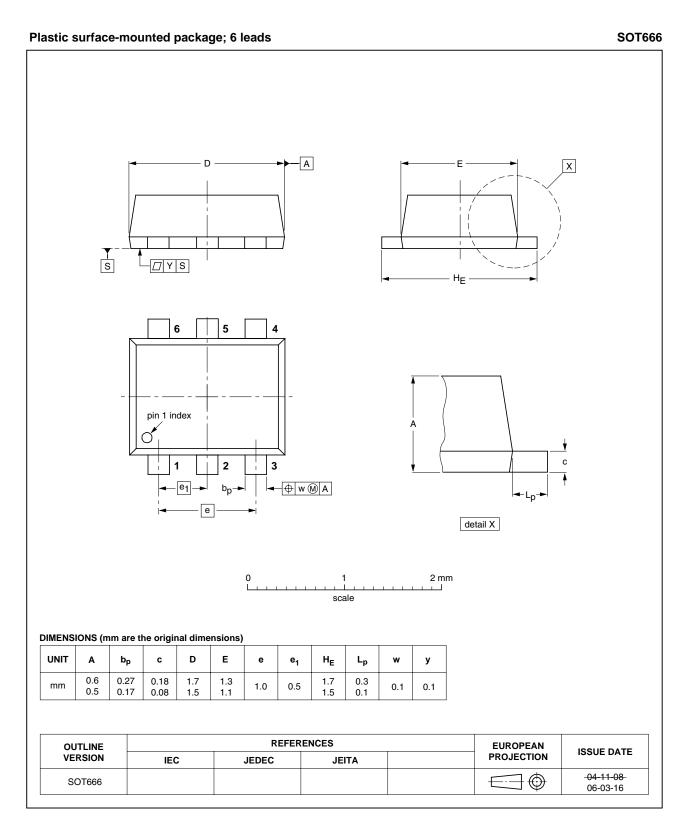


Fig 5. Package outline SOT666

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Plastic surface-mounted package; 6 leads

SOT363

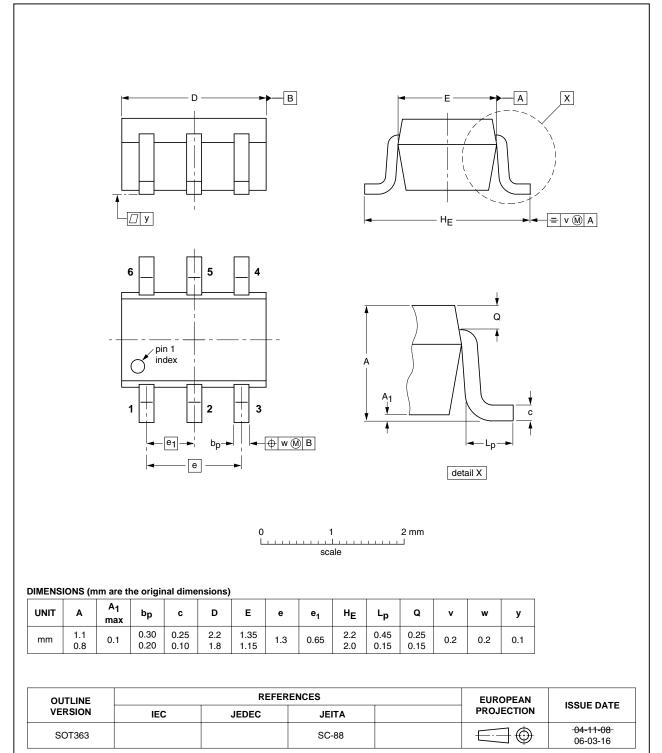


Fig 6. Package outline SOT363 (SC-88)

9. Packing information

Table 9. Packing methods

The -xxx numbers are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description Packing qu		Packing quantity		
			3 000	4000	10 000	
1PS66SB82	SOT666	4 mm pitch, 8 mm tape and reel	·-	-115	-	
1PS88SB82	SOT363	4 mm pitch, 8 mm tape and reel	-115	-	-135	

^[1] For further information and the availability of packing methods see Section 12.

10. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
1PS66SB82_1PS88SB82_4	20100113	Product data sheet	-	1PS66SB82_1PS88SB82_3
Modifications:		•		name NXP Semiconductors, is were made to the technical
	 Table 3 "Pinnii 	ng": updated		
	 Figure 5 "Pack 	kage outline SOT666": u	pdated	
	 Figure 6 "Pack 	kage outline SOT363 (So	C-88)": updated	
1PS66SB82_1PS88SB82_3	20050124	Product data sheet	-	1PS88SB82_2
1PS88SB82_2	20030411	Product specification	-	1PS88SB82_1
1PS88SB82_1	20010216	Product specification	-	-

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11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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